ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_J = 25°C. V_{DD33} = 3.3V, V_{IN_SNS} = 12V, V_{DD25} and REF pins floating, unless otherwise indicated. (Notes 2, 3)

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V_{IN_SNS} Input Characteristics							
V_{VIN_SNS}	V_{IN_SNS} Input Voltage Range		●	0		15	V
R_{VIN_SNS}	V_{IN_SNS} Input Resistance		●	70	90	110	kΩ
TUE_{VIN_SNS}	VIN_ON, VIN_OFF Threshold Total Unadjusted Error	3V ≤ V_{VIN_SNS} ≤ 8V	●			±2.0	% of Reading
		V_{VIN_SNS} > 8V	●			±1.0	% of Reading
	READ_VIN Total Unadjusted Error	3V ≤ V_{VIN_SNS} ≤ 8V	●			±1.5	% of Reading
		V_{VIN_SNS} > 8V	●			±1.0	% of Reading
Temperature Sensor Characteristics							
TUE_TS	Total Unadjusted Error				±1		°C
V_{OUT} Enable Output (V_{OUT_EN} [3:0]) Characteristics							
I_{VOUT_ENn}	Output Sinking Current	Strong Pull-Down Enabled, V_{VOUT_ENn} = 0.4V	●	3	5	8	mA
		Weak Pull-Down Enabled, V_{VOUT_ENn} = 0.4V	●	33	50	60	µA
	Output Leakage Current	Internal Pull-Up Disabled, 0V ≤ V_{VOUT_ENn} ≤ 6V	●			±1	µA
V_{VOUT_VALID}	Minimum V_{DD33} when V_{VOUT_ENn} Valid	V_{VOUT_ENn} ≤ 0.4V	●			1.1	V
V_{OUT} Enable Output (V_{OUT_EN} [7:4]) Characteristics							
I_{VOUT_ENn}	Output Sinking Current	Strong Pull-Down Enabled, V_{OUT_ENn} = 0.1V	●	3	6	9	mA
	Output Leakage Current	0V ≤ V_{VOUT_ENn} ≤ 6V	●			±1	µA
V_{IN} Enable Output (V_{IN_EN}) Characteristics							
I_{VIN_EN}	Output Sinking Current	V_{VIN_EN} = 0.4V	●	3	5	8	mA
	Leakage Current	Internal Pull-Up Disabled, 0V ≤ V_{VIN_EN} ≤ 6V	●			±1	µA
V_{VOUT_VALID}	Minimum V_{DD33} when V_{VOUT_ENn} Valid	V_{VOUT_ENn} ≤ 0.4V	●			1.1	V
EEPROM Characteristics							
Endurance	(Notes 10, 11)	0°C < T_J < 85°C During EEPROM Write Operations	●	10,000			Cycles
Retention	(Notes 10, 11)	T_J < 105°C	●	20			Years
t_{MASS_WRITE}	Mass Write Operation Time (Note 12)	STORE_USER_ALL, 0°C < T_J < 85°C During EEPROM Write Operations	●		440	4100	ms
Digital Inputs SCL, SDA, CONTROL0, CONTROL1, WDI/RESETB, FAULTB00, FAULTB01, FAULTB10, FAULTB11, WP							
V_{IH}	High Level Input Voltage		●	2.1			V
V_{IL}	Low Level Input Voltage		●			1.5	V
V_{HYST}	Input Hysteresis				20		mV
I_{LEAK}	Input Leakage Current	0V ≤ V_{PIN} ≤ 5.5V, SDA, SCL, CONTROL*n* Pins Only	●			±2	µA
		0V ≤ V_{PIN} ≤ V_{DD33} + 0.3V, FAULTB*zn*, WDI/RESETB, WP Pins Only	●			±2	µA